Docket No : 83428US1 (PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE.

In re Patent Application of: Richard L. Henry et al.

Application No.: 10/768.747

Confirmation No.: 7954

Filed: January 23, 2004

Art Unit; 2822

For: Technique for Perfecting the Active Regions of Wide Bandgap Semiconductor Nitride Devices

Exammer: M. F. Guerrero

RESPONSE TO RESTRICTION REQUIREMENT

Customer Window, MS Amendment U.S. Patent and Trademark Office Randolph Building 401 Dulany Street Alexandria, Virginia 22314

Dear Sir.

In response to the restriction requirement set forth in the Office Action mailed March 7, 2006, Applicant hereby provisionally elects claims 1-14 for continued examination.

The Examiner has required restriction between claims 1-14 drawn to a method of making semiconductor devices, and claims 15-20 drawn to a semiconductor device because the Examiner asserts these inventions are independent and distinct.

Dated:

Respectfully submitted

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